TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHC132F,TC74VHC132FN,TC74VHC132FT,TC74VHC132FK

Quad 2-Input Schmitt NAND Gate

Note: xxxFN (JEDEC SOP) is not available in Japan.

The TC74VHC132 is an advanced high speed CMOS 2-INPUT SCHMITT NAND GATE fabricated with silicon gate C^2MOS technology.

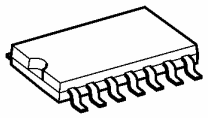
It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

Pin configuration and function are the same as the TC74VHC00 but the inputs have hysteresis and with its schmitt trigger function, the TC74VHC132 can be used as a line receivers which will receive slow input signals.

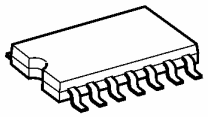
An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 to 3 V systems and two supply systems such as battery back up.

This circuit prevents device destruction due to mismatched supply and input voltages.

TC74VHC132F

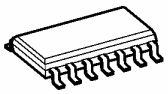


SOP14-P-300-1.27A



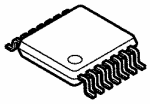
SOP14-P-300-1.27

TC74VHC132FN



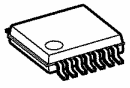
SOL14-P-150-1.27

TC74VHC132FT



TSSOP14-P-0044-0.65A

TC74VHC132FK



VSSOP14-P-0030-0.50

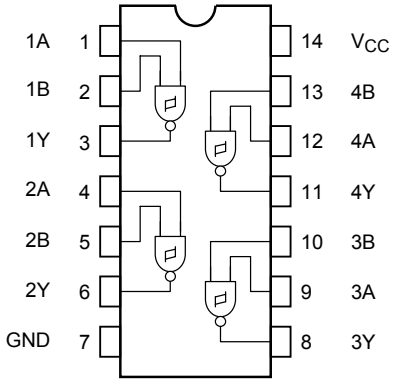
Features

- High speed: t_{pd} = 4.9 ns (typ.) at V_{CC} = 5 V
- Low power dissipation: I_{CC} = 2 μA (max) at Ta = 25°C
- Power down protection is provided on all inputs.
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: $V_{CC\ (opr)}$ = 2 to 5.5 V
- Low noise: V_{OLP} = 0.8 V (max)
- Pin and function compatible with 74ALS132

Weight

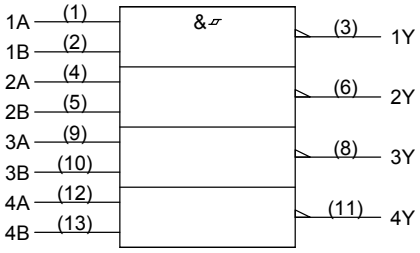
SOP14-P-300-1.27A	: 0.18 g (typ.)
SOP14-P-300-1.27	: 0.18 g (typ.)
SOL14-P-150-1.27	: 0.12 g (typ.)
TSSOP14-P-0044-0.65A	: 0.06 g (typ.)
VSSOP14-P-0030-0.50	: 0.02 g (typ.)

Pin Assignment



(top view)

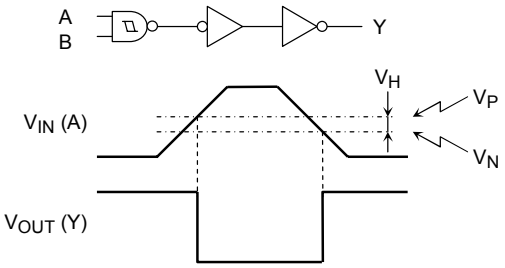
IEC Logic Symbol



Truth Table

A	B	Y
L	L	H
L	H	H
H	L	H
H	H	L

System Diagram, Waveform



Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	−0.5 to 7.0	V
DC input voltage	V_{IN}	−0.5 to 7.0	V
DC output voltage	V_{OUT}	−0.5 to V_{CC} + 0.5	V
Input diode current	I_{IK}	−20	mA
Output diode current	I_{OK}	±20	mA
DC output current	I_{OUT}	±25	mA
DC V_{CC}/ground current	I_{CC}	±50	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{stg}	−65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2.0 to 5.5	V
Input voltage	V_{IN}	0 to 5.5	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{opr}	−40 to 85	°C

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		V_{CC} (V)	Ta = 25°C Min	Ta = 25°C Typ.	Ta = 25°C Max	Ta = −40 to 85°C Min	Ta = −40 to 85°C Max	Unit
Positive threshold voltage	V_P	—		3.0	—	—	2.20	—	2.20	V
				4.5	—	—	3.15	—	3.15	
				5.5	—	—	3.85	—	3.85	
Negative threshold voltage	V_N	—		3.0	0.90	—	—	0.90	—	V
				4.5	1.35	—	—	1.35	—	
				5.5	1.65	—	—	1.65	—	
Hysteresis output voltage	V_H	—		3.0	0.30	—	1.20	0.30	1.20	V
				4.5	0.40	—	1.40	0.40	1.40	
				5.5	0.50	—	1.60	0.50	1.60	
High-level output voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA	2.0	1.9	2.0	—	1.9	—	V
				3.0	2.9	3.0	—	2.9	—	
				4.5	4.4	4.5	—	4.4	—	
			I_{OH} = −4 mA	3.0	2.58	—	—	2.48	—	
			I_{OH} = −8 mA	4.5	3.94	—	—	3.80	—	
Low-level output voltage	V_{OL}	V_{IN} = V_{IH}	I_{OL} = 50 μA	2.0	—	0.0	0.1	—	0.1	V
				3.0	—	0.0	0.1	—	0.1	
				4.5	—	0.0	0.1	—	0.1	
			I_{OL} = 4 mA	3.0	—	—	0.36	—	0.44	
			I_{OL} = 8 mA	4.5	—	—	0.36	—	0.44	
Input leakage current	I_{IN}	V_{IN} = 5.5 V or GND		0 to 5.5	—	—	±0.1	—	±1.0	μA
Quiescent supply current	I_{CC}	V_{IN} = V_{CC} or GND		5.5	—	—	2.0	—	20.0	μA

AC Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V_{CC} (V)	C_L (pF)	Ta = 25°C Min	Ta = 25°C Typ.	Ta = 25°C Max	Ta = −40 to 85°C Min	Ta = −40 to 85°C Max	Unit
Propagation delay time	t_{pLH} t_{pHL}	—	3.3 ± 0.3	15	—	7.6	11.9	1.0	14.0	ns
				50	—	10.1	15.4	1.0	17.5	
			5.0 ± 0.5	15	—	4.9	7.7	1.0	9.0	
				50	—	6.4	9.7	1.0	11.0	
Input capacitance	C_{IN}	—			—	4	10	—	10	pF
Power dissipation capacitance	C_{PD}	(Note)			—	16	—	—	—	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

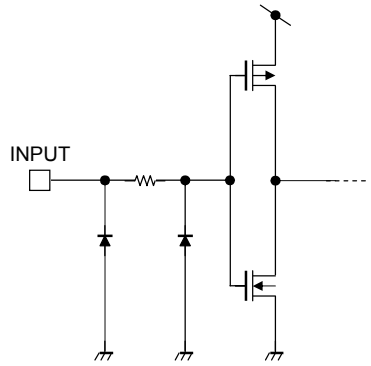
Average operating current can be obtained by the equation:

$$I_{CC\ (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per gate)}$$

Noise Characteristics (input: $t_r = t_f = 3$ ns)

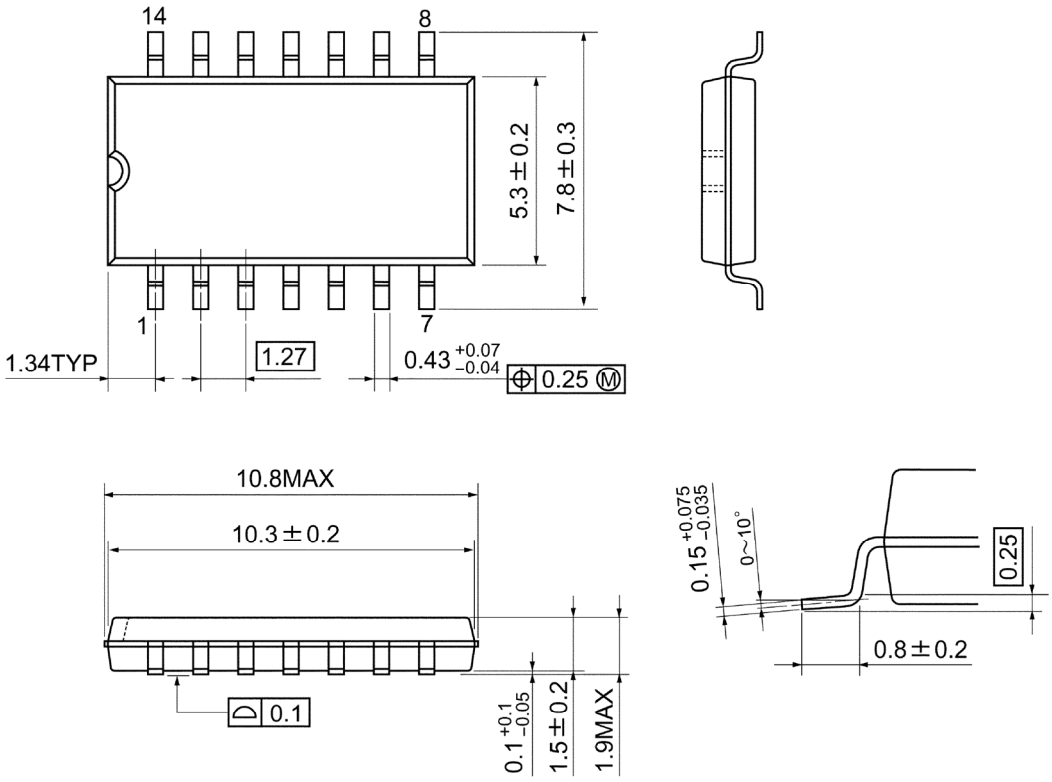
Characteristics	Symbol	Test Condition		Ta = 25°C		Unit
			V_{CC} (V)	Typ.	Max	
Quiet output maximum dynamic V_{OL}	V_{OLP}	C_L = 50 pF	5.0	0.3	0.8	V
Quiet output minimum dynamic V_{OL}	V_{OLV}	C_L = 50 pF	5.0	−0.3	−0.8	V
Minimum high level dynamic input voltage	V_{IHD}	C_L = 50 pF	5.0	—	3.5	V
Maximum low level dynamic input voltage	V_{ILD}	C_L = 50 pF	5.0	—	1.5	V

Input Equivalent Circuit



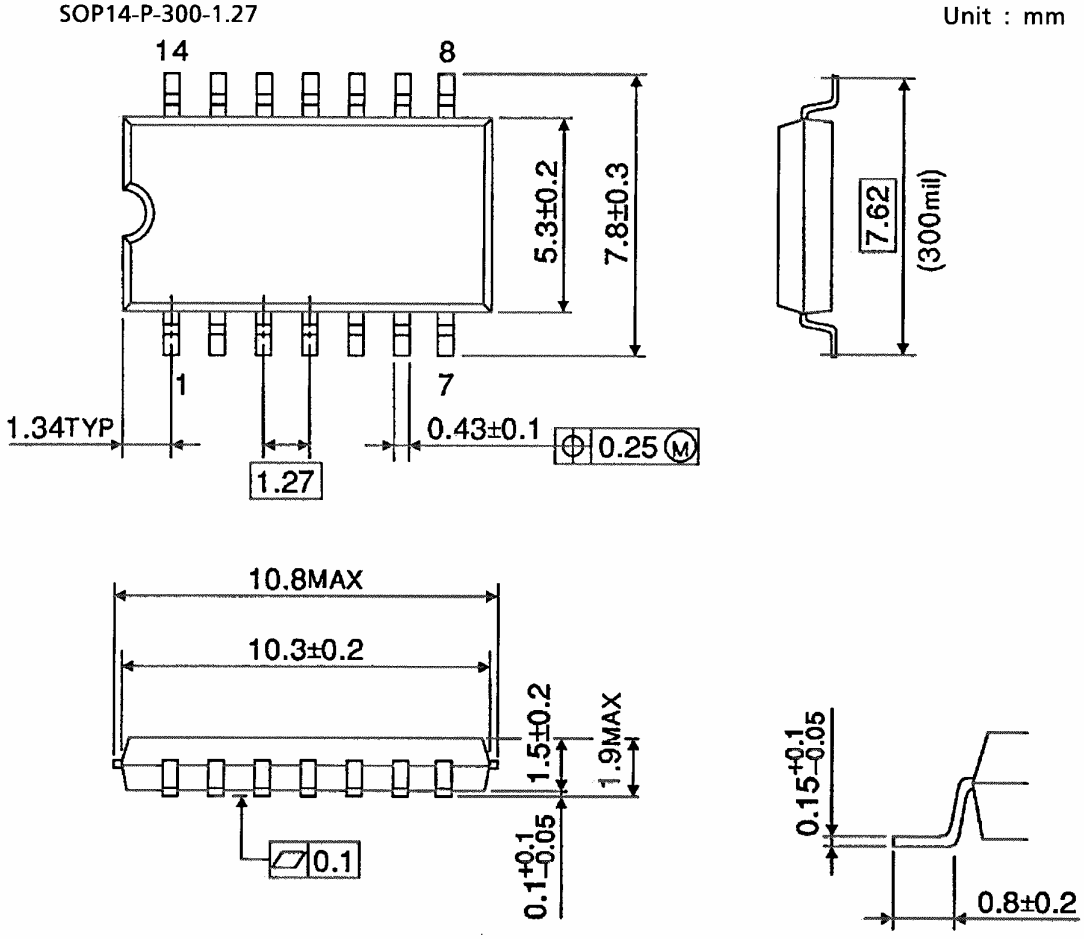
Package Dimensions

SOP14-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)

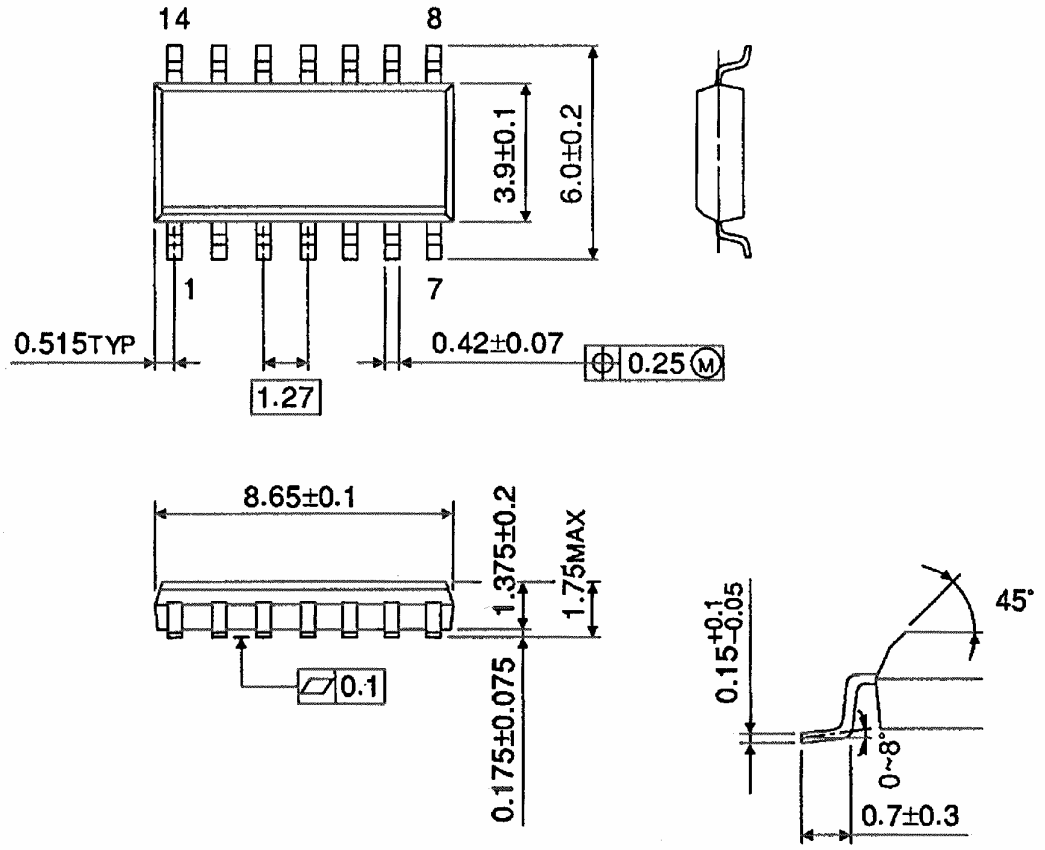
Package Dimensions



Weight: 0.18 g (typ.)

Package Dimensions (Note)

SOL14-P-150-1.27 Unit : mm

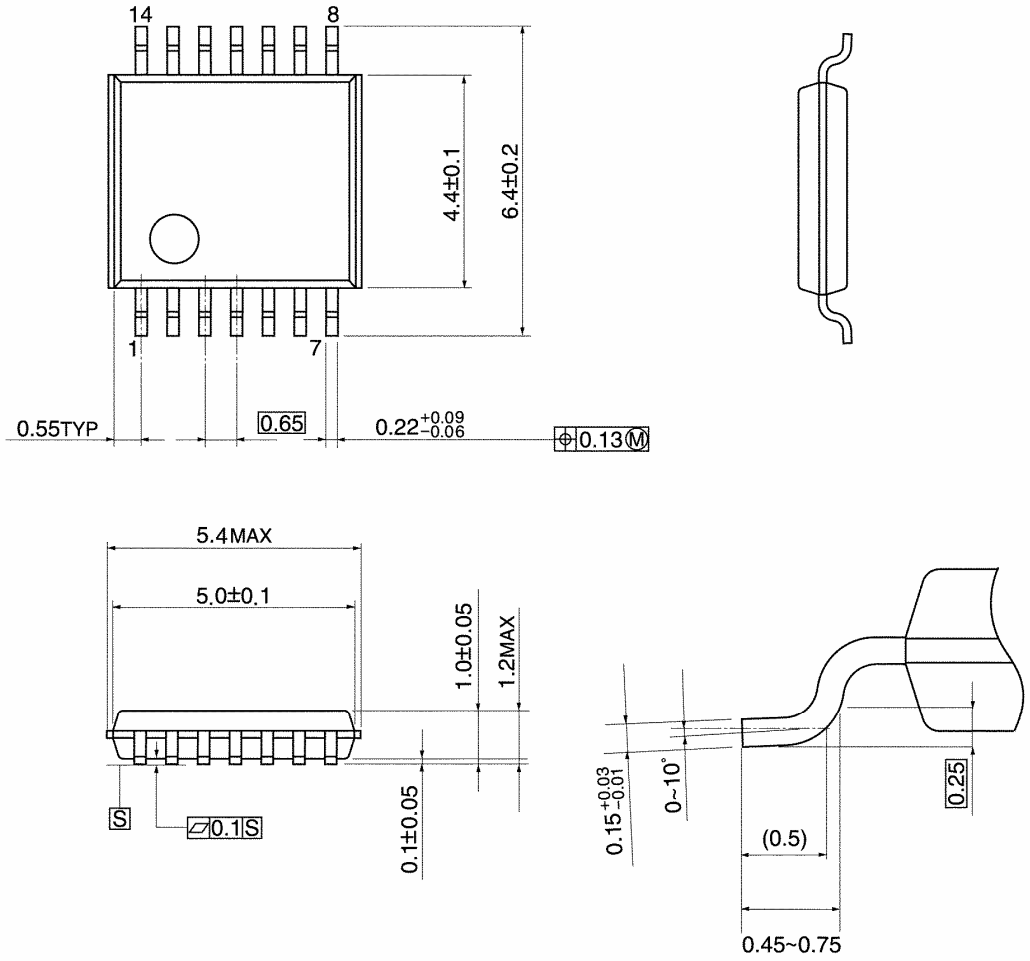


Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

Package Dimensions

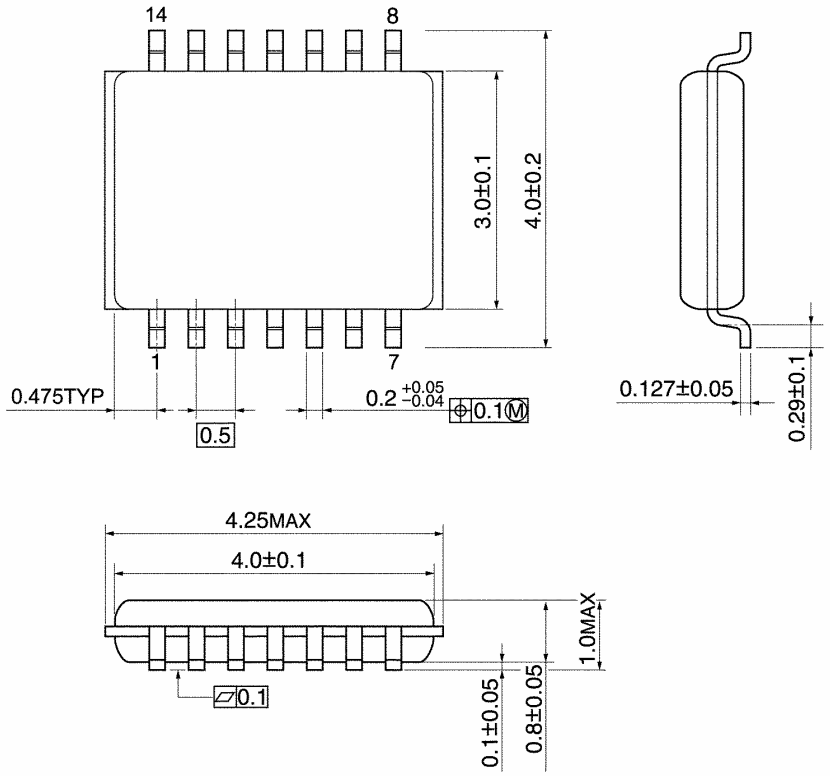
TSSOP14-P-0044-0.65A Unit: mm



Weight: 0.06 g (typ.)

Package Dimensions

VSSOP14-P-0030-0.50 Unit: mm



Weight: 0.02 g (typ.)

Note: Lead (Pb)-Free Packages

SOP14-P-300-1.27A SOL14-P-150-1.27 TSSOP14-P-0044-0.65A VSSOP14-P-0030-0.50

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